Low-power configurable gate with voltage-level translatorRev. 5 — 15 August 2012Product data sheet

1. General description

The 74AUP1T57 provides low-power, low-voltage configurable logic gate functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer. All inputs can be connected to V_{CC} or GND.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 2.3 V to 3.6 V.

The 74AUP1T57 is designed for logic-level translation applications with input switching levels that accept 1.8 V low-voltage CMOS signals, while operating from either a single 2.5 V or 3.3 V supply voltage.

The wide supply voltage range ensures normal operation as battery voltage drops from 3.6 V to 2.3 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger inputs make the circuit tolerant to slower input rise and fall times across the entire V_{CC} range.

2. Features and benefits

- Wide supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 1.5 \ \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

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3. Ordering information

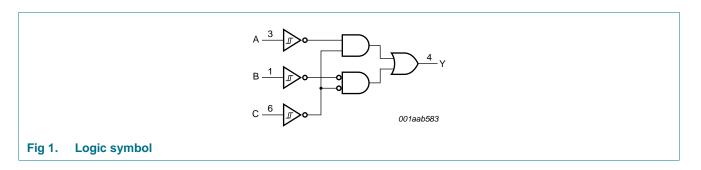
Table 1. Ordering	g information			
Type number	Package			
	Temperature range	Name	Description	Version
74AUP1T57GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74AUP1T57GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886
74AUP1T57GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm	SOT891
74AUP1T57GN	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm	SOT1115
74AUP1T57GS	–40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm	SOT1202

4. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74AUP1T57GW	a7
74AUP1T57GM	a7
74AUP1T57GF	a7
74AUP1T57GN	a7
74AUP1T57GN	a7

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

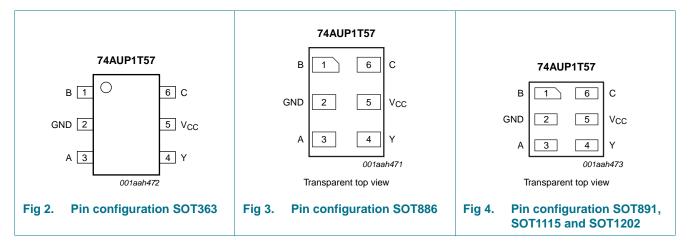
5. Functional diagram



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6. Pinning information

6.1 Pinning



6.2 Pin description

SymbolPinDescriptionB1data inputGND2ground (0 V)A3data inputY4data outputV _{CC} 5supply voltageC6data input	Table 3.	Pin description	
GND2ground (0 V)A3data inputY4data outputV _{CC} 5supply voltage	Symbol	Pin	Description
A3data inputY4data outputV _{CC} 5supply voltage	В	1	data input
Y4data outputV _{CC} 5supply voltage	GND	2	ground (0 V)
V _{CC} 5 supply voltage	A	3	data input
	Y	4	data output
	V _{CC}	5	supply voltage
		6	data input

7. Functional description

Table 4. Func	tion table ^[1]		
Input			Output
С	В	Α	Y
L	L	L	Н
L	L	Н	L
L	Н	L	Н
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	Н

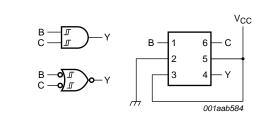
[1] H = HIGH voltage level; L = LOW voltage level.

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7.1 Logic configurations

Table 5.Function selection table

Logic function	Figure
2-input AND	see <u>Figure 5</u>
2-input AND with both inputs inverted	see Figure 8
2-input NAND with inverted input	see <u>Figure 6</u> and <u>7</u>
2-input OR with inverted input	see <u>Figure 6</u> and <u>7</u>
2-input NOR	see Figure 8
2-input NOR with both inputs inverted	see Figure 5
2-input XNOR	see Figure 9
Inverter	see Figure 10
Buffer	see Figure 11



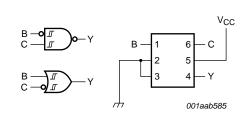
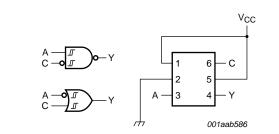


Fig 5. 2-input AND gate or 2-input NOR gate with both inputs inverted







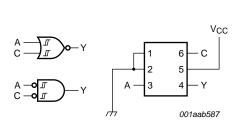
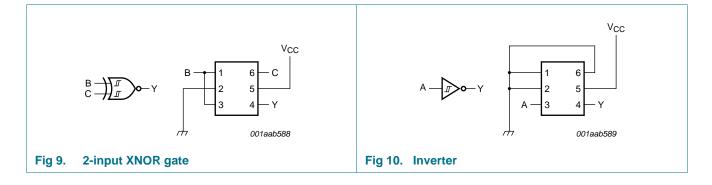
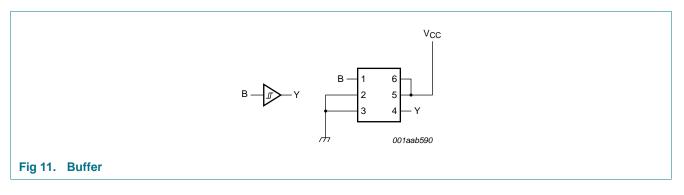


Fig 8. 2-input NOR gate or 2-input AND gate with both inputs inverted



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Limiting values 8.

Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode	<u>[1]</u> –0.5	+4.6	V
I _O	output current	$V_{O} = 0 V$ to V_{CC}	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	٥C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SC-88 package: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K. [2] For XSON6 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

Recommended operating conditions 9.

Table 7.	Recommended operating cond	ditions			
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		2.3	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V_{CC}	V
		Power-down mode; $V_{CC} = 0 V$	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C					
V _{T+}	positive-going threshold	V_{CC} = 2.3 V to 2.7 V	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.75	-	1.16	V
V _{T-}	negative-going threshold	V_{CC} = 2.3 V to 2.7 V	0.35	-	0.60	V
	voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_H=V_{T+}-V_{T-})$				
		V_{CC} = 2.3 V to 2.7 V	0.23	-	0.60	V
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	0.25	-	0.56	V
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 μ A; V _{CC} = 2.3 V to 3.6 V	$V_{CC}-0.1$	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		$I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.9	-	-	V
		$I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.72	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		$I_0 = 20 \ \mu A; V_{CC} = 2.3 \ V \text{ to } 3.6 \ V$	-	-	0.10	V
		$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.31	V
		$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.44	V
I _I	input leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.1	μA
ΔI_{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	1.2	μΑ
Δl _{CC}	additional supply current	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$	<u>[1]</u> _	-	-	μA
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } I_{O} = 0 \text{ A}$	[2] _	-	-	μΑ
CI	input capacitance	$V_{CC} = 0$ V to 3.6 V; $V_I = GND$ or V_{CC}	-	0.8	-	, pF
C _O	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF
	-40 °C to +85 °C					•
V _{T+}	positive-going threshold	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0.60	-	1.10	V
	voltage	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.75	-	1.19	V
V _{T-}	negative-going threshold	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0.35	-	0.60	V
	voltage	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.50	-	0.85	V
V _H	hysteresis voltage	$(V_{H} = V_{T+} - V_{T-})$				-
- 11	, stor cole i shago	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0.10	-	0.60	V
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.15	-	0.56	V
			0.10		0.00	v

Low-power configurable gate with voltage-level translator

Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

	Conditions		21		Unit
-level output voltage	$V_I = V_{T+}$ or V_{T-}				
	I_{O} = -20 μ A; V _{CC} = 2.3 V to 3.6 V	$V_{CC}-0.1$	-	-	V
	$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.97	-	-	V
	$I_0 = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.85	-	-	V
	$I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.67	-	-	V
	$I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.55	-	-	V
level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
	I_{O} = 20 μ A; V_{CC} = 2.3 V to 3.6 V	-	-	0.1	V
	$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.33	V
	I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
	$I_0 = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.33	V
	$I_0 = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.45	V
leakage current	$V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.5	μA
r-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
onal power-off	$V_{\rm I}$ or $V_{\rm O} = 0$ V to 3.6 V;	-	-	±0.5	μA
ge current y current	$V_{CC} = 0 V \text{ to } 0.2 V$ $V_I = \text{GND or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 2.3 V \text{ to } 3.6 V$	-	-	1.5	μA
onal supply current	$V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V; } I_{O} = 0 \text{ A}$	[1] -		1	μA
onal supply current	$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } I_{O} = 0 \text{ A}$	[2] -	-		
o +125 °C	$v_{\rm CC} = 3.0$ v to 3.0 v, $r_0 = 0$ A	<u> </u>	-	12	μA
ve-going threshold	V_{CC} = 2.3 V to 2.7 V	0.60		1 10	V
je	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.00	-		V
ive-going threshold	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0.33			V
je	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.33			V
resis voltage	$(V_{H} = V_{T+} - V_{T-})$	0.40		- - - - - - - 0.1 - 0.33 - 0.45 - 0.45 - 0.45 - ± 0.5 - ± 0.64 - 0.60 - 0.60 - 0.56	v
lesis voltage	$\frac{(V_{H} - V_{I+} - V_{I-})}{V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}}$	0.10		0.60	V
	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	0.10	-		V
		0.15	-	0.56	V
-level output voltage	$V_{I} = V_{T+}$ or V_{T-} $I_{O} = -20 \ \mu\text{A}; V_{CC} = 2.3 \ \text{V to } 3.6 \ \text{V}$	V _{CC} – 0.11			V
	$I_0 = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.77	-		V
	$I_0 = -2.3$ mA; $V_{CC} = 2.3$ V $I_0 = -3.1$ mA; $V_{CC} = 2.3$ V	1.67	-	-	V
	$I_0 = -3.1 \text{ mA}, V_{CC} = 2.3 \text{ V}$ $I_0 = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$		-	-	V
	$I_0 = -2.7$ mA, $V_{CC} = 3.0$ V $I_0 = -4.0$ mA; $V_{CC} = 3.0$ V	2.40	-	-	V
level output voltage	$V_{I} = V_{T+}$ or V_{T-}	2.30	-	-	V
level output voltage	$V_{I} = V_{T+} \text{ of } V_{T-}$ $I_{O} = 20 \ \mu\text{A}; V_{CC} = 2.3 \ \text{V to } 3.6 \ \text{V}$			0.11	V
		-	-		-
	$I_0 = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-		V
	$I_0 = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-		-
		-	-		V
	0 00	-	-		V
leakage current	$v_1 = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V	-	-	±0.75	μA
leak et	age current	$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ stage current $V_{I} = \text{GND to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ All information provided in this document is subject to legal disclar	$I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ - $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ -	$I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ - - $I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ - - sage current $V_I = \text{GND to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ - All information provided in this document is subject to legal disclaimers. -	Io = 2.7 mA; V _{CC} = 3.0 V - - 0.36 Io = 4.0 mA; V _{CC} = 3.0 V - - 0.50 tage current V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V - - ± 0.75 All information provided in this document is subject to legal disclaimers.

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At recom	mended operating conditions	s; voltages are referenced to GND (gro	und = $0 V$).			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{OFF}	power-off leakage current	$V_{\rm I}~{\rm or}~V_{\rm O}$ = 0 V to 3.6 V; $V_{\rm CC}$ = 0 V	-	-	±0.75	μA
ΔI_{OFF}	additional power-off leakage current	V_i or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 2.3 \text{ V to } 3.6 \text{ V}$	-	-	3.5	μΑ
ΔI_{CC}	additional supply current	V_{CC} = 2.3 V to 2.7 V; I_O = 0 A	<u>[1]</u> -	-	7	μA
		V_{CC} = 3.0 V to 3.6 V; I_O = 0 A	[2] _	-	22	μA

Table 8. Static characteristics ... continued

[1] One input at 0.3 V or 1.1 V, other input at $V_{CC} \mbox{ or GND}.$

[2] One input at 0.45 V or 1.2 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 13.

Symbol	Symbol Parameter	Conditions		25 °C			–40 °C to +125 °C		
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
V _{CC} = 2.	3 V to 2.7 V; V _I = 1.6	65 V to 1.95 V						1	
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]						
		C _L = 5 pF	2.1	3.6	5.5	0.5	6.8	7.5	ns
		C _L = 10 pF	2.6	4.1	6.2	1.0	7.9	8.7	ns
		C _L = 15 pF	2.9	4.6	6.8	1.0	8.7	9.6	ns
		C _L = 30 pF	3.8	5.8	8.2	1.5	10.8	11.9	ns
V _{CC} = 2.	3 V to 2.7 V; V _I = 2.3	3 V to 2.7 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]						
		C _L = 5 pF	1.7	3.4	5.4	0.5	6.0	6.6	ns
		C _L = 10 pF	2.1	4.0	6.2	1.0	7.1	7.9	ns
		C _L = 15 pF	2.5	4.5	6.7	1.0	7.9	8.7	ns
		C _L = 30 pF	3.3	5.6	8.2	1.5	10.0	11.0	ns
V _{CC} = 2.	3 V to 2.7 V; V _I = 3.0) V to 3.6 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]						
		C _L = 5 pF	1.4	3.2	4.9	0.5	5.5	6.1	ns
		C _L = 10 pF	1.8	3.7	5.7	1.0	6.5	7.2	ns
		C _L = 15 pF	2.2	4.2	6.3	1.0	7.4	8.2	ns
		C _L = 30 pF	3.0	5.4	7.8	1.5	9.5	10.5	ns
V _{CC} = 3.	0 V to 3.6 V; V _I = 1.6	65 V to 1.95 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	[2]						
		C _L = 5 pF	2.0	2.9	3.9	0.5	8.0	8.8	ns
		C _L = 10 pF	2.5	3.5	4.6	1.0	8.5	9.4	ns
		C _L = 15 pF	2.8	3.9	5.2	1.0	9.1	10.1	ns
		C _L = 30 pF	3.6	5.1	6.6	1.5	9.8	10.8	ns

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Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	_
V _{CC} = 3.	0 V to 3.6 V; $V_1 = 2.3$	3 V to 2.7 V	1						
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	<u>2]</u>						
		$C_L = 5 \text{ pF}$	1.6	2.8	4.2	0.5	5.3	5.9	ns
		C _L = 10 pF	2.0	3.4	4.9	1.0	6.1	6.8	ns
		C _L = 15 pF	2.3	3.9	5.5	1.0	6.8	7.5	ns
		C _L = 30 pF	3.1	5.0	6.9	1.5	8.5	9.4	ns
V _{CC} = 3.	0 V to 3.6 V; V _I = 3.0) V to 3.6 V							
t _{pd}	propagation delay	A, B, C to Y; see Figure 12	2]						
		$C_L = 5 \text{ pF}$	1.3	2.8	4.2	0.5	4.7	5.2	ns
		C _L = 10 pF	1.7	3.3	4.9	1.0	5.7	6.3	ns
		C _L = 15 pF	2.0	3.8	5.5	1.0	6.2	6.9	ns
		C _L = 30 pF	2.8	4.9	7.0	1.5	7.8	8.6	ns
T _{amb} = 2	25 °C								
C _{PD}	power dissipation	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$	3]						
	capacitance	V_{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	pF
		$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	-	4.3	-	-	-	-	pF

Table 9. Dynamic characteristics ... continued

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL}

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}{}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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12. Waveforms

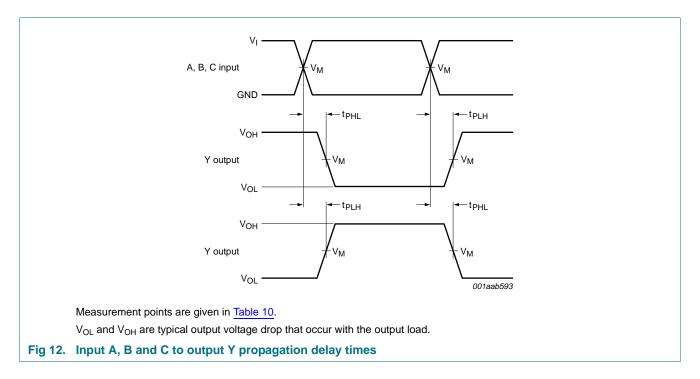


Table 10. Measurement points

Supply voltage	Output	Input		
V _{CC}	V _M	V _M	VI	t _r = t _f
2.3 V to 3.6 V	$0.5 \times V_{CC}$	$0.5 \times V_I$	1.65 V to 3.6 V	≤ 3.0 ns

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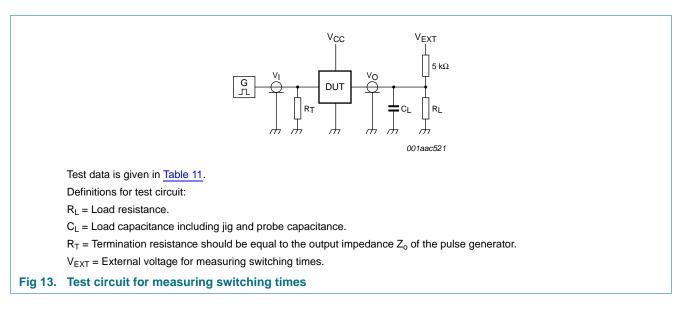


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
2.3 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$, for measuring propagation delays, setup and hold times and pulse width $R_L = 1 M\Omega$.

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13. Package outline

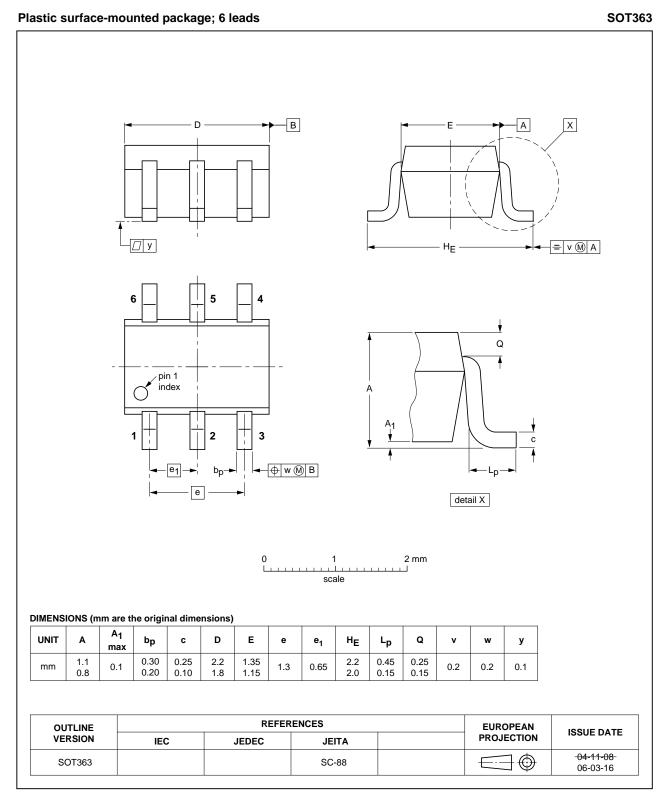


Fig 14. Package outline SOT363 (SC-88)

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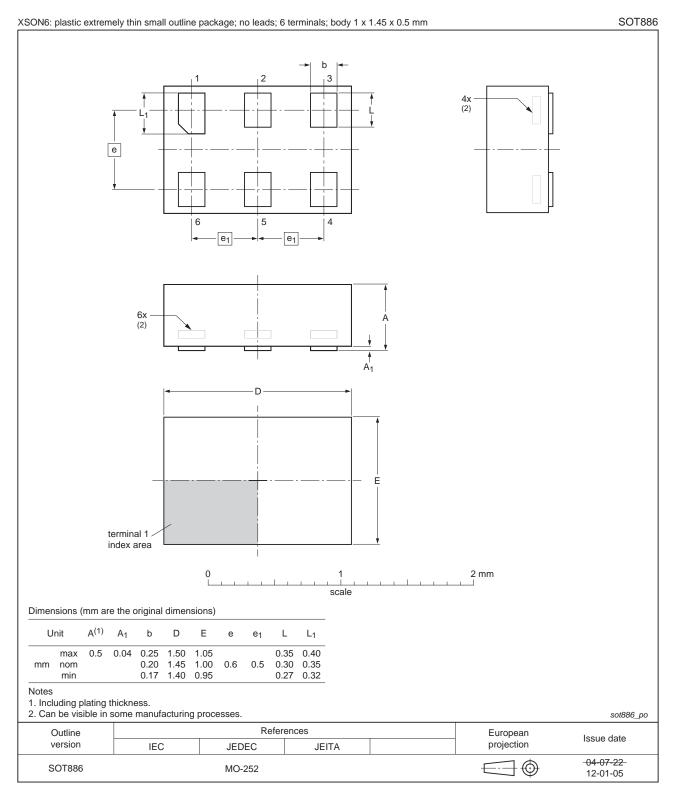


Fig 15. Package outline SOT886 (XSON6)

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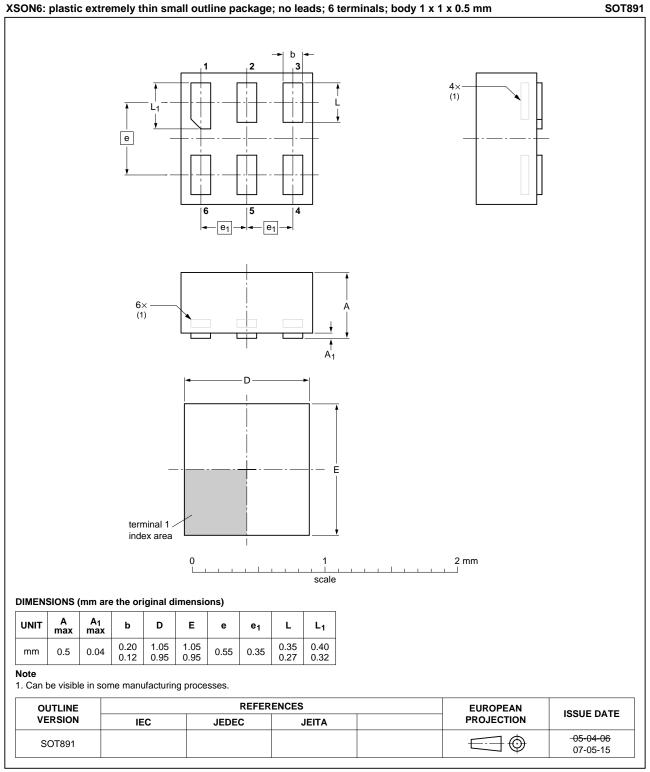
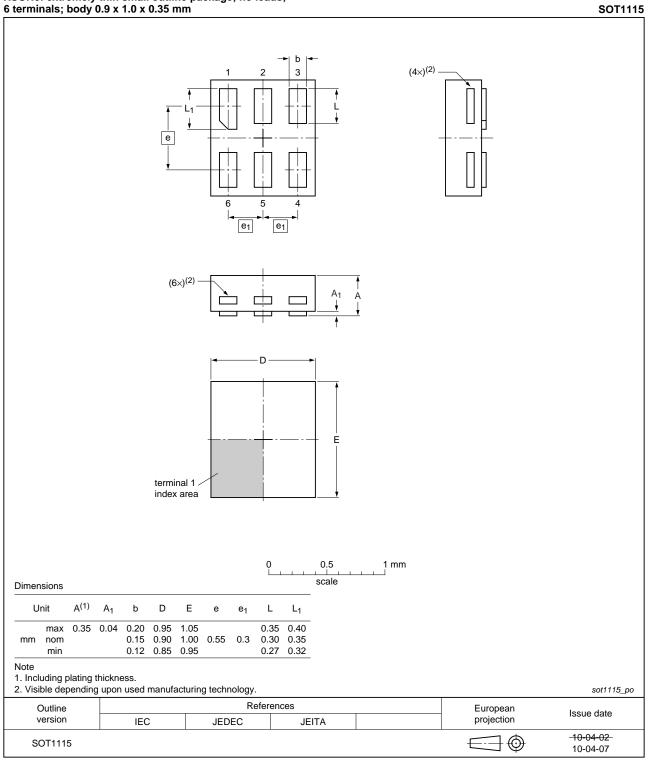


Fig 16. Package outline SOT891 (XSON6)

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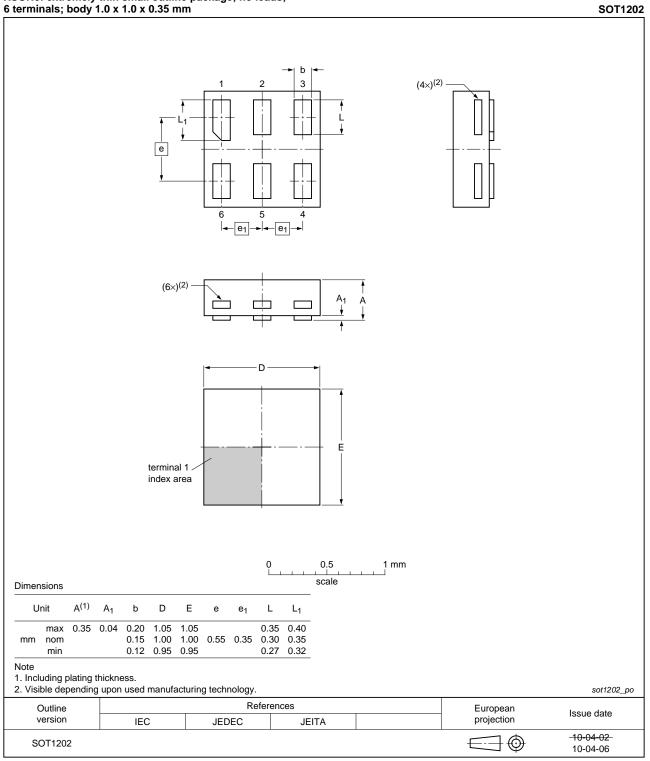


XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm

Fig 17. Package outline SOT1115 (XSON6)

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XSON6: extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm

Fig 18. Package outline SOT1202 (XSON6)

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14. Abbreviations

Table 12. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal Oxide Semiconductor		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		

15. Revision history

Table 13. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1T57 v.5	20120815	Product data sheet	-	74AUP1T57 v.4
Modifications:	 Package outling 	ne drawing of SOT886 (<u>Figure 15</u>)	modified.	
74AUP1T57 v.4	20111201	Product data sheet	-	74AUP1T57 v.3
74AUP1T57 v.3	20100721	Product data sheet	-	74AUP1T57 v.2
74AUP1T57 v.2	20090803	Product data sheet	-	74AUP1T57 v.1
74AUP1T57 v.1	20080103	Product data sheet	-	-

16. Legal information

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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